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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10064409	FILING DATE 07/11/2002	CLASS 365	SUBCLASS 258	GAU 2818	EXAMINER Beech
**APPLICANTS: Hsu Ching-Hsiang; Yang Ching-Sung; 438 68.2					
**CONTINUING DATA VERIFIED: THIS APPLICATION IS A DIV OF 09/865,432 05/29/2001 Booth					
** FOREIGN APPLICATIONS VERIFIED:					
PG-PUB <input type="checkbox"/> DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>			
Foreign priority claimed <input type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 conditions met <input type="checkbox"/> yes <input type="checkbox"/> no Verified and Acknowledged Examiners's initials				ATTORNEY DOCKET NO EMEP0021USA	
TITLE : Structure of an embedded channel write/erase flash memory cell and fabricating method thereof					
U.S. DEPT. OF COMM./PAT. & TM.-PTO-435L (Rev. 12-94)					

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G.
Assistant Examiner			
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drwg.	Figs. Drwg. Print Fig.
		Primary Examiner	
<input type="checkbox"/> TERMINAL DISCLAIMER		Applicant Examiner	
		PREPARED FOR ISSUE	
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